

The T9S0 SCR employs a Center-Fired amplifying gate structure which allows the SCR to be reliably operated at high di/dt and high dv/dt conditions in phase control applications.

#### FEATURES:

- Low On-State Voltage
- High di/dt Capability
- High dv/dt Capability
- Hermetic Ceramic Package
- Excellent Surge and I<sup>2</sup>t Ratings

#### APPLICATIONS:

- DC Power Supplies
- Plating Supplies
- Welding Supplies

#### ORDERING INFORMATION

Select the complete 12 digit Part Number using the table below.  
EXAMPLE: **T9S0082803DH** is an 800V-2850A SCR with 200ma IGT and 12 inch gate and cathode potential leads.

| PART        | Voltage Rating<br>$V_{DRM}-V_{RRM}$ | Voltage Code | Current Rating<br>$I_{tavg}$ | Current Code | Turn-Off<br>$T_q$ | Gate<br>$I_{GT}$ | Leads     |
|-------------|-------------------------------------|--------------|------------------------------|--------------|-------------------|------------------|-----------|
| <b>T9S0</b> | 800V                                | <b>08</b>    | 2850A                        | <b>28</b>    | <b>0</b>          | <b>3</b>         | <b>DH</b> |
|             | 600V                                | <b>06</b>    |                              |              |                   |                  |           |
|             | 400V                                | <b>04</b>    |                              |              | 400us typ.        | 200ma            | 12"       |
|             |                                     |              |                              |              |                   |                  |           |
|             |                                     |              |                              |              |                   |                  |           |
|             |                                     |              |                              |              |                   |                  |           |

Revised: 9/22/2009

**Absolute Maximum Ratings**

| Characteristic   | Symbol            | Rating      | Units            |
|--|-------------------|-------------|------------------|
| Repetitive Peak Voltage  | $V_{DRM}-V_{RRM}$ | 400 - 800   | Volts            |
| Average On-State Current, $T_C=70^{\circ}C$                                  | $I_{T(Avg.)}$     | 2850        | A                |
| RMS On-State Current, $T_C=72^{\circ}C$                                      | $I_{T(RMS)}$      | 4477        | A                |
| Average On-State Current, $T_C=55^{\circ}C$                                  | $I_{T(Avg.)}$     | 3300        | A                |
| RMS On-State Current, $T_C=55^{\circ}C$                                      | $I_{T(RMS)}$      | 5184        | A                |
| Peak One Cycle Surge Current, 60Hz, $V_R=0V$                                 | $I_{TSM}$         | 37,000      | A                |
| Peak One Cycle Surge Current, 50Hz, $V_R=0V$                                 | $I_{TSM}$         | 34,884      | A                |
| Fuse Coordination $I^2t$ , 60Hz  | $I^2t$            | 5.70E+06    | A <sup>2</sup> s |
| Fuse Coordination $I^2t$ , 50Hz  | $I^2t$            | 6.08E+06    | A <sup>2</sup> s |
| Critical Rate-of-Rise of On-State Current<br>Repetitive                      | di/dt             | 100         | A/us             |
| Critical Rate-of-Rise of On-State Current<br>Non-Repetitive                  | di/dt             | 200         | A/us             |
| Critical Rate-of-Rise of Off-State Voltage<br>Linear to $\frac{2}{3}V_{DRM}$ | dv/dt             | 1000        | V/us             |
| Peak Gate Power, 100us   | $P_{GM}$          | 16          | Watts            |
| Average Gate Power   | $P_{G(avg)}$      | 5           | Watts            |
| Operating Temperature  | $T_j$             | -20 to +125 | $^{\circ}C$      |
| Storage Temperature  | $T_{Stg.}$        | -50 to +150 | $^{\circ}C$      |
| Approximate Weight   |                   | 0.65        | lb               |
|  |                   | 0.29        | Kg               |
| Mounting Force   |                   | 5500-6000   | lbs              |
|  |                   | 24.5 - 26.7 | Knewtons         |

Information presented is based upon manufacturers testing and projected capabilities. This information is subject to change without notice. The manufacturer makes no claim as to suitability for use, reliability, capability or future availability of this product.

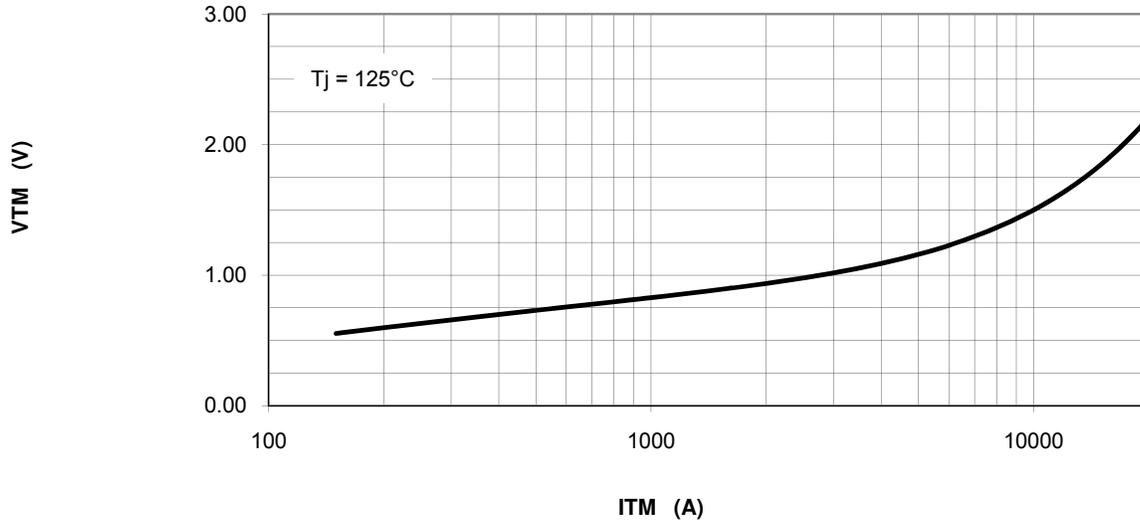
**Electrical Characteristics, Tj=25°C unless otherwise specified**

| Characteristic                  | Symbol                                      | Test Conditions                                    | Rating                            |     |          | Units |
|---------------------------------|---|--|-----------------------------------|-----|----------|-------|
|                                 |   |  | min                               | typ | max      |       |
| Repetitive Peak Leakage Current | $I_{DRM}/I_{RRM}$                           | Tj=125°C, $V_{DRM}$ =Rated                         |                                   |     | 150      | ma    |
| Peak On-State Voltage           | $V_{TM}$                                    | Tj=25°C, $I_{TM}$ =1500A                           |                                   |     | 1.15     | V     |
| $V_{TM}$ Model, Low Level       | $V_0$                                       | Tj=125°C   |                                   |     | 0.722    | V     |
|                                 | $V_{TM} = V_0 + r \cdot I_{TM}$             | $r$  | 15% $I_{TM}$ - $\pi \cdot I_{TM}$ |     | 8.83E-02 | mΩ    |
| $V_{TM}$ Model, High Level      | $V_0$                                       | Tj=125°C   |                                   |     | 0.784    | V     |
|                                 | $V_{TM} = V_0 + r \cdot I_{TM}$             | $r$  | $\pi \cdot I_{TM} - I_{TSM}$      |     | 7.11E-02 | mΩ    |
| $V_{TM}$ Model, Hiç 4-Term      | A   | Tj=125°C   |                                   |     | -0.342   |       |
|                                 | $V_{TM} = A + B \cdot \ln(I_{TM}) +$        | B  | 15% $I_{TM} - I_{TSM}$            |     | 0.199    |       |
|                                 | $C \cdot (I_{TM}) + D \cdot (I_{TM})^{1/2}$ | C  |                                   |     | 9.66E-05 |       |
|                                 |   | D  |                                   |     | -0.00962 |       |
| Turn-On Delay Time              | $t_d$                                       | $V_D = 0.5 \cdot V_{DRM}$<br>Gate Drive: 40V - 20Ω |                                   | 1.5 |          | us    |
| Turn-Off Time                   | $t_q$                                       | Tj=125°C<br>$dv/dt = 20V/us$ to 80% $V_{DRM}$      |                                   | 400 |          | us    |
| Gate Trigger Current            | $I_{GT}$                                    | Tj=25°C $V_D = 12V$                                | 30                                | 90  | 200      | ma    |
| Gate Trigger Voltage            | $V_{GT}$                                    |  | 0.6                               | 1.6 | 3.0      | V     |
| Peak Reverse Gate Voltage       | $V_{GRM}$                                   |  |                                   |     | 5        | V     |

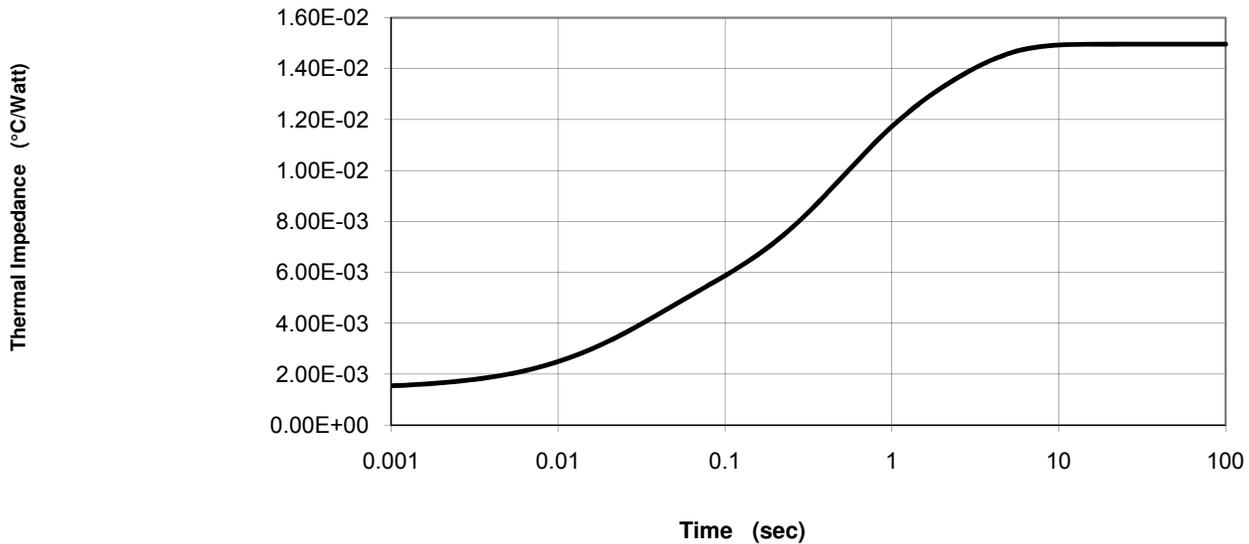
**Thermal Characteristics**

| Characteristic   | Symbol         | Test Conditions    | Rating   |          |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
|--|----------------|--------------------|----------|----------|--|--|-----|---|---|---|---|--------|----------|----------|----------|----------|--------|----------|----------|----------|----------|
|  |                |                    | max      | Units    |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| Thermal Resistance   |                |                    |          |          |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| Junction to Case   | $R\theta_{jc}$ | Double side cooled | 0.015    | °C/Watt  |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| Case to Sink   | $R\theta_{cs}$ | Double side cooled | 0.0025   | °C/Watt  |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| Thermal Impedance Model  |                |                    |          |          |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
|  | $Z\theta_{jc}$ | Double side cooled |          |          |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| $Z\theta_{jc}(t) = \sum(A(N) \cdot (1 - \exp(-t/\tau(N))))$ where: <table style="display: inline-table; vertical-align: middle;"> <tr> <td>N =</td> <td>1</td> <td>2</td> <td>3</td> <td>4</td> </tr> <tr> <td>A(N) =</td> <td>1.42E-03</td> <td>2.97E-03</td> <td>6.07E-03</td> <td>4.50E-03</td> </tr> <tr> <td>τ(N) =</td> <td>5.95E-05</td> <td>2.76E-02</td> <td>4.01E-01</td> <td>2.00E+00</td> </tr> </table> |                |                    |          |          |  |  | N = | 1 | 2 | 3 | 4 | A(N) = | 1.42E-03 | 2.97E-03 | 6.07E-03 | 4.50E-03 | τ(N) = | 5.95E-05 | 2.76E-02 | 4.01E-01 | 2.00E+00 |
| N =  | 1              | 2                  | 3        | 4        |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| A(N) =   | 1.42E-03       | 2.97E-03           | 6.07E-03 | 4.50E-03 |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |
| τ(N) =   | 5.95E-05       | 2.76E-02           | 4.01E-01 | 2.00E+00 |  |  |     |   |   |   |   |        |          |          |          |          |        |          |          |          |          |

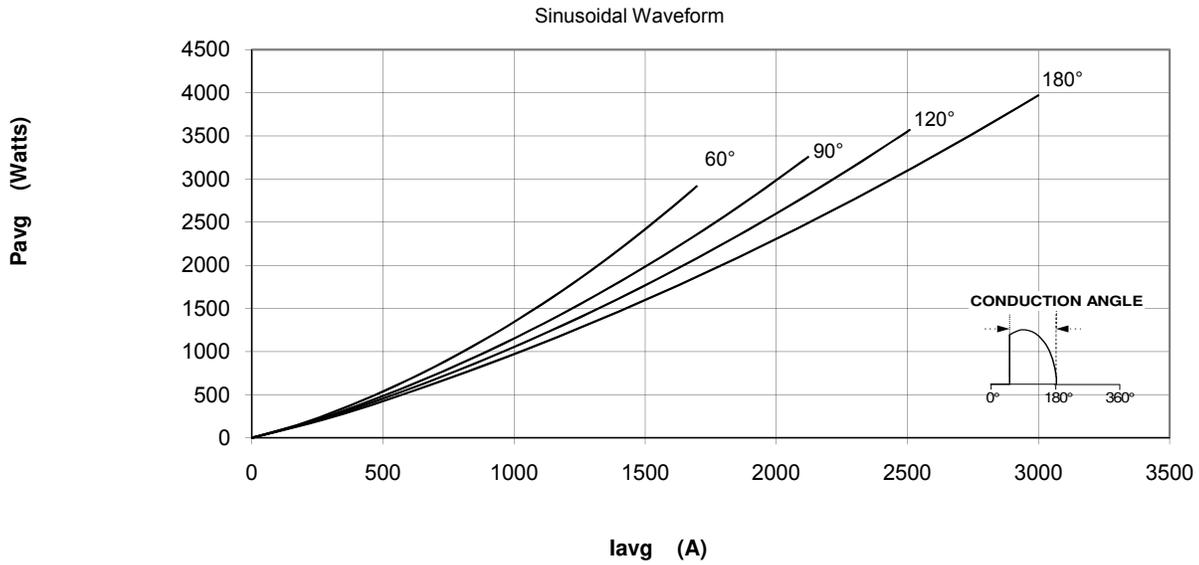
### Maximum On-State Voltage Drop



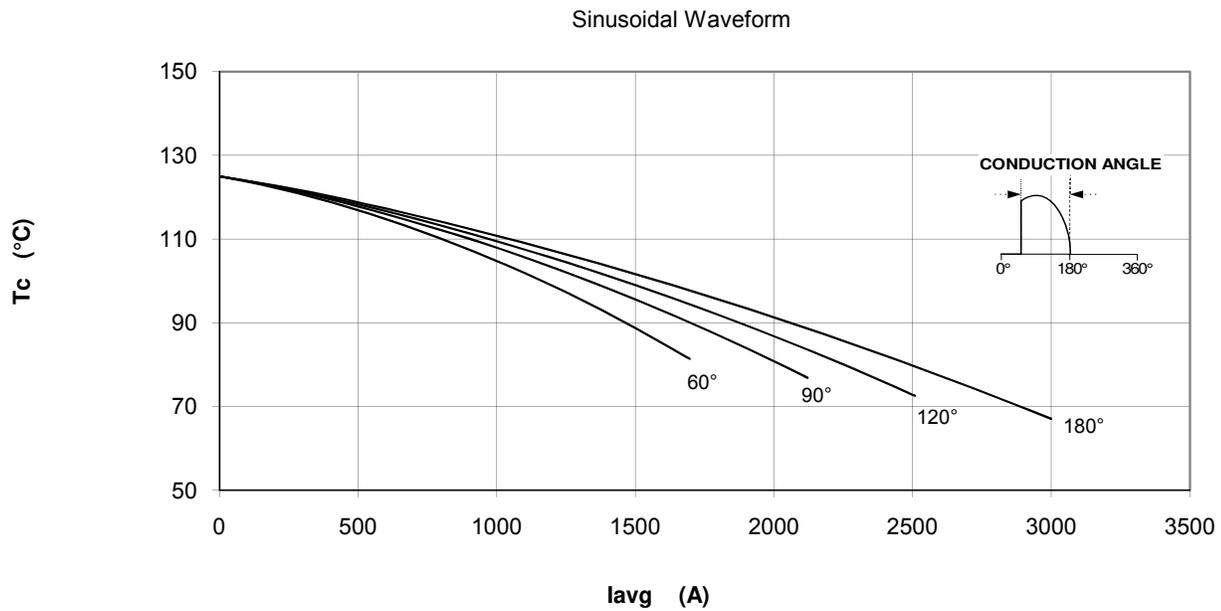
### MAXIMUM TRANSIENT THERMAL IMPEDANCE



### Maximum On-State Power Dissipation

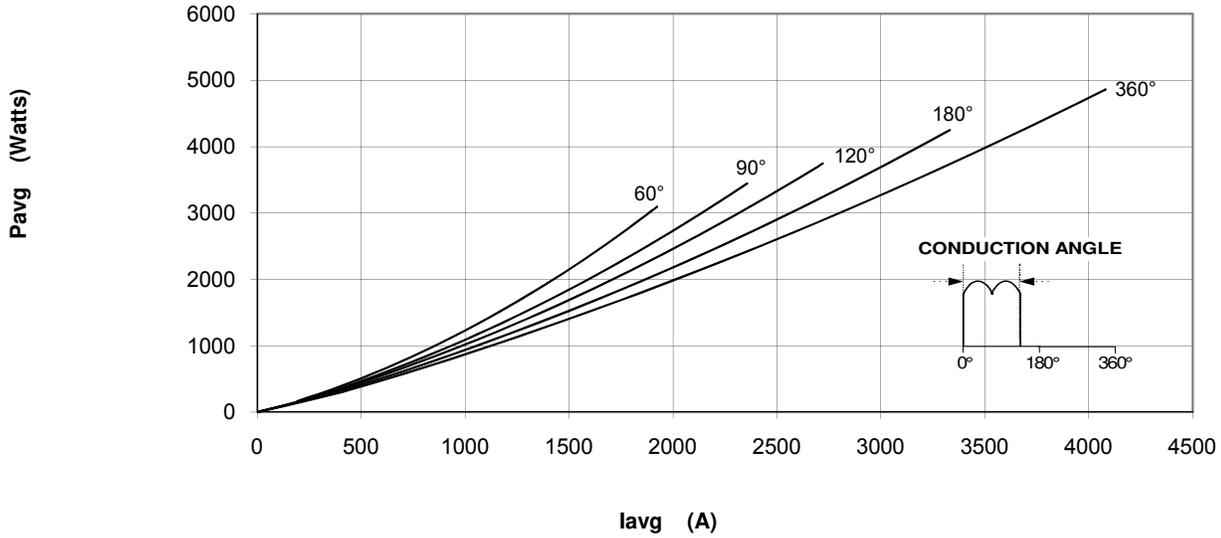


### Maximum Allowable Case Temperature



## Maximum On-State Power Dissipation

Square Waveform



## Maximum Allowable Case Temperature

Square Waveform

